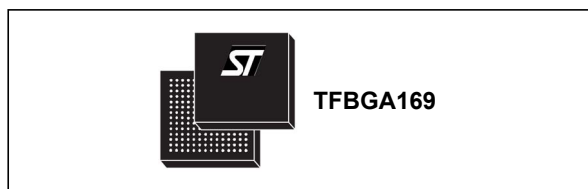


Fully integrated GPS/Galileo/GLONASS/BeiDou/QZSS receiver with high performance processing capability

Datasheet - production data



Features

- STMicroelectronics® positioning receiver with 48 tracking channels and 2 fast acquisition channels supporting GPS, Galileo, GLONASS, BeiDou and QZSS systems
- Single die standalone receiver embedding RF Front-End and low noise amplifier
- -162 dBm indoor sensitivity (tracking mode)
- Fast TTFF < 1 s in Hot start and 30 s in Cold Start
- High performance ARM946 MCU (up to 196 MHz)
- 256 Kbyte embedded SRAM
- FSMC external memory interface (NOR and SRAM)
- External SQI Flash interface
- 8 free running timers/ counters (32 bit)
- Real Time Clock (RTC) circuit
- 32-bit Watch-dog timer
- 3 UARTs
- 1 I²C master interface
- 1 Synchronous Serial Port (SSP, Motorola-SPI supported)
- USB2.0 full speed (12 MHz) with integrated physical layer transceiver
- 2 Controller Area Network (CAN) (STA8090EXGB only)
- 8 channels ADC (10 bits)
- 1 Secure-Digital Multimedia Memory Card Interfaces (SDMMC)

- 1 Multichannel Serial Port (MSP)
- Power Management Unit (PMU) embedding switching regulator
- Operating condition:
 - Main voltage regulator (V_{INL}): 1.6 V to 4.3 V
 - Backup voltage (V_{INB}): 1.6 V to 4.3 V
 - Digital voltage (V_{DD}): 1.0 V to 1.32 V
 - RF core voltage (V_{CC}): 1.2 V $\pm$ 10%
 - IO Ring Voltage (V_{ddIO}): 1.8 V $\pm$ 5% or 3.3 V $\pm$ 10%
- Package:
 - TFBGA169 9 x 9 x 1.2 mm 0.65 pitch
- Ambient temperature range: -40/ +85 °C

Description

STA8090EXG belongs to Teseo III family products.

STA8090EXG is a highly integrated System-On-Chip GNSS receiver designed for high-flexible and cost effective solution addressing, trackers, hand-held, in-dash navigation and Telematics applications.

STA8090EXG embeds the new ST GNSS positioning engine capable of receiving signals from multiple satellite navigation systems, including GPS, Galileo, GLONASS, BeiDou QZSS.

The STA8090EXG combines a high performance ARM946 microprocessor with I/O capabilities and enhanced peripherals. It embeds innovative power management unit for power consumption optimization.

STA8090EXGBD can run also TESEO-DRAW the STMicroelectronics dead reckoning firmware.

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1 Overview

STA8090EXG is one of the part number of Teseo III STA8090x series.

STA8090EXG is a highly integrated System-On-Chip GNSS receiver designed for high-flexible and cost effective solution addressing hand-held, in-dash navigation and Telematics applications.

STA8090EXG embeds the new ST GNSS positioning engine capable of receiving signals from multiple satellite navigation systems, including the US GPS, European Galileo, Russia's GLONASS, Chinese BeiDou and Japan's QZSS.

The STA8090EXG ability of tracking simultaneously the signals from multiple satellites regardless of their constellation, make this chip capable of delivering exceptional accuracy in urban canyons and in the environments where buildings and other obstructions make satellite visibility challenging.

STA8090EXGBD can be offered also bundled with STMicroelectronics dead reckoning firmware called TESEO-DRAW; TESEO-DRAW firmware is a multi-sensors data fusion hub for Teseo family IC's.

STA8090EXG embeds innovative power management unit with switching regulator for power consumption optimization.

The extended voltage supply range from 1.6 V to 4.3 V, the 1.8 V and 3.3 V I/O compliance support make the STA8090EXG the suitable solution for different user applications.

The STA8090EXG combines a high performance ARM946 microprocessor with I/O capabilities and enhanced peripherals. It embeds FSMC for interfacing external memories (NOR and SRAM).

It supports USB2.0 standard at full speed (12 Mbps) with on-chip PHY.

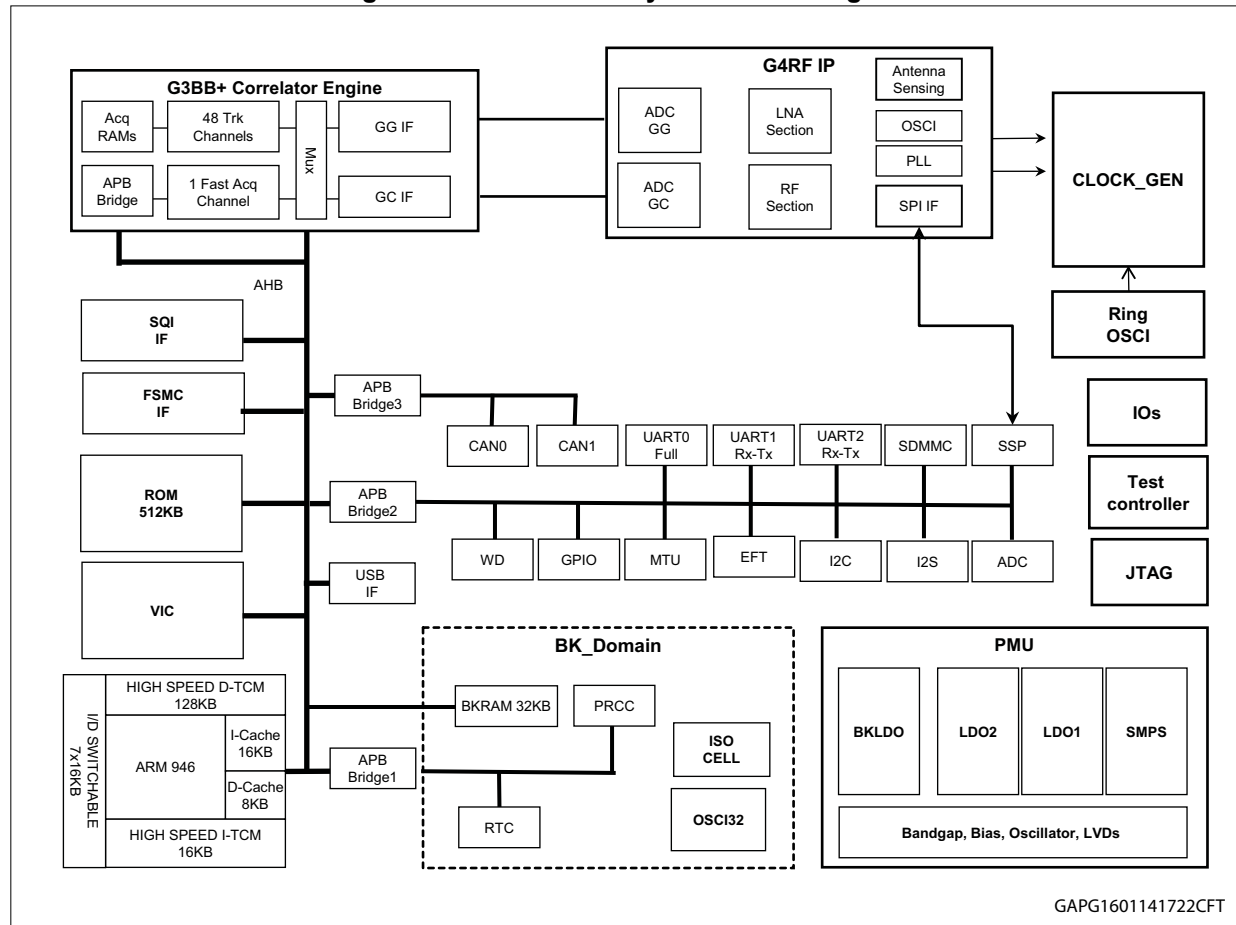
The chip embeds backup logic with real time clock.

The STA8090EXG, using STMicroelectronics CMOSRF Technology, is housed in a FBGA169 (9 x 9 x 1.2 mm) 0.65mm pitch package.

2 Pin description

2.1 Block diagram

Figure 1. STA8090EXG system block diagram



2.2 TFBG_A169 ball out

Table 1. TFBGA169 ball out with CAN (STA8090EXGBx)

	1	2	3	4	5	6	7	8	9	10	11	12	13	
A	VINM	VINM	FMSC_DATA8	FMSC_DATA5	FMSC_DATA3	FMSC_DATA1	UART0_DSR	UART0_CTS	VINL1	VOL1	GND	VINB	VOB	A
B	VLX	VLX	FMSC_DATA13	FMSC_DATA11	FMSC_DATA9	FMSC_DATA0	UART0_RX	UART0_RTS	SPI_DO	SPI_DI	SPI_CLK	SPI_CSN	GND	B
C	GND	GND	FMSC_DATA12	FMSC_DATA4	FMSC_DATA6	UART0_DCD	UART0_TX	UART2_RX	ADC_IN5	ADC_IN6	ADC_IN2	ADC_IN1	ADC_IN4	C
D	VOM	FMSC_DATA15	FMSC_DATA2	FMSC_DATA7	GND	UART0_DTR	UART2_TX	GND	ADC_IN8	VDD_ADC	ADC_IN3	ADC_IN7	Reserved	D
E	VDD_ANA	GND	FMSC_CS1	FMSC_DATA10	FMSC_DATA14	VDDIO_R1	VDDIO_FSMC	GPIO1	GPIO0	RTC_XTI	RTC_XTO	CAN0_RX	I2C_SD	E
F	GND	FMSC_BLN1	FMSC_CS0	FMSC_BLN0	FMSC_WEN	GND	GND	VDDD	GND	WAKEUP1	WAKEUP0	CAN0_TX	I2C_CLK	F
G	FMSC_ADD16	FMSC_ADV	FMSC_CLK	FMSC_CS2	GND	GND	GND	VDDD	RSTn	VDD_SQI	SQI_SIO0/SI	SQI_SIO1/SO	SQI_SIO2	G
H	FMSC_ADD13	FMSC_OUTEN	FMSC_WTN	NC	TDO	VDDD	VDDD	VDDD	STDBYn	PMU_CFG	SQI_SIO3	SQI_CLK	SQI_CEN	H
J	FMSC_ADD14	FMSC_ADD10	FMSC_ADD3	FMSC_ADD15	TDI	TCK	TRSTn	GPIO19	GPIO11	STDBY_OUT	GPIO3	GPIO2	VCC_PLL	J
K	FMSC_ADD11	FMSC_ADD9	FMSC_ADD5	FMSC_ADD6	FMSC_ADD12	TMS	MMC_D1	MMC_D3	GPIO13	GND	GND	XTAL_IN	XTAL_OUT	K
L	USB_DP	FMSC_ADD7	FMSC_ADD21	FMSC_ADD1	FMSC_ADD8	FMSC_ADD17	MMC_CLK	GPIO12	GPIO10	GND	GND	ANT_SENSE2	VCC_CHAIN	L
M	USB_DM	FMSC_ADD0	FMSC_ADD2	FMSC_ADD4	FMSC_ADD20	FMSC_ADD22	MMC_D2	TP_IF_P	GND_LNA	GND_LNA	GND_LNA	GND	ANT_SENSE1	M
N	GND	VDDIO_R2	FMSC_ADD19	FMSC_ADD18	FMSC_ADD23	MMC_D0	MMC_CMD	TP_IF_N	VCC_RF	LNA_IN	VOL2	VINL2	GND	N
	1	2	3	4	5	6	7	8	9	10	11	12	13	



Table 2. TFBGA169 ball out no CAN

	1	2	3	4	5	6	7	8	9	10	11	12	13	
A	VINM	VINM	FMSC_DATA8	FMSC_DATA5	FMSC_DATA3	FMSC_DATA1	UART0_DSR	UART0_CTS	VINL1	VOL1	GND	VINB	VOB	A
B	VLX	VLX	FMSC_DATA13	FMSC_DATA11	FMSC_DATA9	FMSC_DATA0	UART0_RX	UART0_RTS	SPI_DO	SPI_DI	SPI_CLK	SPI_CSN	GND	B
C	GND	GND	FMSC_DATA12	FMSC_DATA4	FMSC_DATA6	UART0_DCD	UART0_TX	UART2_RX	ADC_IN5	ADC_IN6	ADC_IN2	ADC_IN1	ADC_IN4	C
D	VOM	FMSC_DATA15	FMSC_DATA2	FMSC_DATA7	GND	UART0_DTR	UART2_TX	GND	ADC_IN8	VDD_ADC	ADC_IN3	ADC_IN7	Reserved	D
E	VDD_ANA	GND	FMSC_CS1	FMSC_DATA10	FMSC_DATA14	VDDIO_R1	VDDIO_FSMC	GPIO1	GPIO0	RTC_XT1	RTC_XTO	UART0_RX	I2C_SD	E
F	GND	FMSC_BLN1	FMSC_CS0	FMSC_BLN0	FMSC_WEN	GND	GND	VDDD	GND	WAKEUP1	WAKEUP0	UART0_TX	I2C_CLK	F
G	FMSC_ADD16	FMSC_ADV	FMSC_CLK	FMSC_CS2	GND	GND	GND	VDDD	RSTn	VDD_SQI	SQI_SIO0/SI	SQI_SIO1/SO	SQI_SIO2	G
H	FMSC_ADD13	FMSC_OUTEN	FMSC_WTN	NC	TDO	VDDD	VDDD	VDDD	STDBYn	PMU_CFG	SQI_SIO3	SQI_CLK	SQI_CEN	H
J	FMSC_ADD14	FMSC_ADD10	FMSC_ADD3	FMSC_ADD15	TDI	TCK	TRSTn	GPIO19	GPIO11	STDBY_OUT	GPIO3	GPIO2	VCC_PLL	J
K	FMSC_ADD11	FMSC_ADD9	FMSC_ADD5	FMSC_ADD6	FMSC_ADD12	TMS	MMC_D1	MMC_D3	GPIO13	GND	GND	XTAL_IN	XTAL_OUT	K
L	USB_DP	FMSC_ADD7	FMSC_ADD21	FMSC_ADD1	FMSC_ADD8	FMSC_ADD17	MMC_CLK	GPIO12	GPIO10	GND	GND	ANT_SENSE2	VCC_CHAIN	L
M	USB_DM	FMSC_ADD0	FMSC_ADD2	FMSC_ADD4	FMSC_ADD20	FMSC_ADD22	MMC_D2	TP_IF_P	GND_LNA	GND_LNA	GND_LNA	GND	ANT_SENSE1	M
N	GND	VDDIO_R2	FMSC_ADD19	FMSC_ADD18	FMSC_ADD23	MMC_D0	MMC_CMD	TP_IF_N	VCC_RF	LNA_IN	VOL2	VINL2	GND	N
	1	2	3	4	5	6	7	8	9	10	11	12	13	

2.3 Power supply pins

Table 3. Power supply pins

Symbol	I/O voltage	I/O	Description	STA8090EXG
VCC_CHAIN	1.2 V	PWR	Analog supply voltage for RF chain (1.2 V)	L13
VCC_PLL	1.2 V	PWR	Analog supply voltage for PLL RF (1.2 V)	J13
VCC_RF	1.2 V	PWR	Analog supply voltage for RF (1.2 V)	N9
VDD_ADC	1.8 V	PWR	Digital supply voltage for ADC (1.8 V)	D10
VDD_SQI	1.8 V or 3.3 V	PWR	Digital supply voltage for SQI	G10
VDDD	1.1 V	PWR	Digital supply voltage	F8, G8, H6, H7, H8
VDDIO_FSMC	1.8 V or 3.3 V	PWR	Digital supply voltage for I/O ring FSMC (1.8 V or 3.3V)	E7
VDDIO_R1	1.8 V or 3.3 V	PWR	Digital supply voltage for I/O ring 1 (1.8 V or 3.3V)	E6
VDDIO_R2	3.3 V	PWR	Digital supply voltage for I/O ring 2 (3.3 V)	N2
VINB	1.6 V - 4.3 V	PWR	Backup LDO input supply voltage (1.6 V to 4.3 V)	A12
VINL1	1.6 V - 4.3 V	PWR	LDO1 input supply voltage (1.6 V to 4.3 V)	A9
VINL2	1.6 V - 4.3 V	PWR	LDO2 input supply voltage (1.6 V to 4.3 V)	N12
VINM	1.6 V - 4.3 V	PWR	SMPS coil input supply (1.6 V to 4.3 V)	A1, A2
VDD_ANA	1.6 V - 4.3 V	PWR	SMPS input supply (1.6 V to 4.3 V)	E1
VLX	0 V - 4.3 V	PWR	SMPS coil output	B1, B2
VOB	1.0 V	PWR	LDO backup output voltage (1.0 V)	A13
VOL1	1.1 V or 1.8 V	PWR	LDO1 output voltage: PMU_CFG = high -> 1.1 V (it can be also configured to 1.2 V) PMU_CFG = low -> 1.8 V	A10
VOL2	1.2 V	PWR	LDO2 output voltage (1.2 V)	N11
VOM	1.1 V or 1.8 V	PWR	SMPS output voltage PMU_CFG = high -> 1.8 V PMU_CFG = low -> 1.1 V (it can be also configured to 1.2 V)	D1
GND	GND	GND	Ground	A11, B13, C1, C2, D5, D8, E2, F1, F6, F7, F9, G5, G6, G7, K10, K11, L10, L11, M12, N1, N13
GND_LNA	GND	GND	Ground	M9, M10, M11

2.4 Main function pins

Table 4. Main function pins

Symbol	I/O voltage	I/O	Description	STA8090EXG
ADC_IN1	1.4 V – 0 V typ range	I	ADC Analog input [1]	C12
ADC_IN2	1.4 V – 0 V typ range	I	ADC Analog input [2]	C11
ADC_IN3	1.4 V – 0 V typ range	I	ADC Analog input [3]	D11
ADC_IN4	1.4 V – 0 V typ range	I	ADC Analog input [4]	C13
ADC_IN5	1.4 V – 0 V typ range	I	ADC Analog input [5]	C9
ADC_IN6	1.4 V – 0 V typ range	I	ADC Analog input [6]	C10
ADC_IN7	1.4 V – 0 V typ range	I	ADC Analog input [7]	D12
ADC_IN8	1.4 V – 0 V typ range	I	ADC Analog input [8]	D9
PMU_CFG	1.0 V	I	Power management unit config pin High -> VOL1 = 1.1 V, VOM = 1.8 V Low -> VOL1 = 1.8 V, VOM = 1.1 V	H10
RSTn	1.0 V	I	Reset Input with Schmitt-Trigger characteristics and noise filter.	G9
RTC_XTI	1.0 V (max)	I	Input of the 32 KHz oscillator amplifier circuit and input of the internal real time clock circuit.	E10
RTC_XTO	1.0 V (max)	O	Output of the oscillator amplifier circuit.	E11
STDBY_OUT	1.0 V	O	When low, indicates the chip is in Standby mode	J10
STDBYn	1.0 V	I	When low, the chip is forced in Standby Mode - All pins in high impedance except the ones powered by Backup supply	H9
WAKEUP0	1.0 V	I	WAKEUP from STANDBY mode	F11
WAKEUP1	1.0 V	I	WAKEUP from STANDBY mode	F10

2.5 Test / emulated dedicated pins

Table 5. Test/emulated dedicated pins

Symbol	I/O voltage	I/O	Description	STA8090EXG
TCK	VDDIO_R2	I	JTAG Test Clock	J6
TDI	VDDIO_R2	I	JTAG Test Data In	J5
TDO	VDDIO_R2	O	JTAG Test Data Out	H5
TMS	VDDIO_R2	I	JTAG Test Mode Select	K6
TRSTn	VDDIO_R2	I	JTAG Test Circuit Reset	J7
TP_IF_N	1.2 V	O	Diff.Test Point for IF — Neg.	N8
TP_IF_P	1.2 V	O	Diff.Test Point for IF — Pos.	M8

2.6 FSMC external memory interface pins

Table 6. FSMC external memory interface pins

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
FSMC_ADD0	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD0	FSMC EMI address bus	M2
		I/O	AF1, AF2, AF3	GPIO32	General purpose I/O #32	
FSMC_ADD1	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD1	FSMC EMI address bus	L4
		I/O	AF1, AF2, AF3	GPIO33	General purpose I/O #33	
FSMC_ADD2	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD2	FSMC EMI address bus	M3
		I/O	AF1, AF2, AF3	GPIO34	General purpose I/O #34	
FSMC_ADD3	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD3	FSMC EMI address bus	J3
		I/O	AF1, AF2, AF3	GPIO35	General purpose I/O #35	
FSMC_ADD4	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD4	FSMC EMI address bus	M4
		I/O	AF1, AF2, AF3	GPIO36	General purpose I/O #36	
FSMC_ADD5	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD5	FSMC EMI address bus	K3
		I/O	AF1, AF2, AF3	GPIO37	General purpose I/O #37	
FSMC_ADD6	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD6	FSMC EMI address bus	K4
		I/O	AF1, AF2, AF3	GPIO38	General purpose I/O #38	
FSMC_ADD7	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD7	FSMC EMI address bus	L2
		I/O	AF1, AF2, AF3	GPIO39	General purpose I/O #39	
FSMC_ADD8	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD8	FSMC EMI address bus	L5
		I/O	AF1, AF2, AF3	GPIO40	General purpose I/O #40	
FSMC_ADD9	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD9	FSMC EMI address bus	K2
		I/O	AF1, AF2, AF3	GPIO41	General purpose I/O #41	
FSMC_ADD10	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD10	FSMC EMI address bus	J2
		I/O	AF1, AF2, AF3	GPIO42	General purpose I/O #42	

Table 6. FSMC external memory interface pins (continued)

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
FSMC_ADD11	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD11	FSMC EMI address bus	K1
		I/O	AF1, AF2, AF3	GPIO43	General purpose I/O #43	
FSMC_ADD12	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD12	FSMC EMI address bus	K5
		I/O	AF1, AF2, AF3	GPIO44	General purpose I/O #44	
FSMC_ADD13	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD13	FSMC EMI address bus.	H1
		I/O	AF1, AF2, AF3	GPIO45	General purpose I/O #45	
FSMC_ADD14	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD14	FSMC EMI address bus	J1
		I/O	AF1, AF2, AF3	GPIO46	General purpose I/O #46	
FSMC_ADD15	VDDIO_FSMC	O	AF0 (default)	FSMC_ADD15	FSMC EMI address bus	J4
		I/O	AF1, AF2, AF3	GPIO47	General purpose I/O #47	
FSMC_ADD16	VDDIO_FSMC	O	—	FSMC_ADD16	FSMC EMI address bus	G1
FSMC_ADD17	VDDIO_FSMC	O	—	FSMC_ADD17	FSMC EMI address bus	L6
FSMC_ADD18	VDDIO_FSMC	O	—	FSMC_ADD18	FSMC EMI address bus	N4
FSMC_ADD19	VDDIO_FSMC	O	—	FSMC_ADD19	FSMC EMI address bus	N3
FSMC_ADD20	VDDIO_FSMC	O	—	FSMC_ADD20	FSMC EMI address bus	M5
FSMC_ADD21	VDDIO_FSMC	O	—	FSMC_ADD21	FSMC EMI address bus	L3
FSMC_ADD22	VDDIO_FSMC	O	—	FSMC_ADD22	FSMC EMI address bus	M6
FSMC_ADD23	VDDIO_FSMC	O	—	FSMC_ADD23	FSMC EMI address bus	N5
FSMC_ADV	VDDIO_FSMC	O	—	FSMC_ADV	FSMC EMI Address Valid	G2
FSMC_BLN0	VDDIO_FSMC	O	—	FSMC_BLN0	FSMC EMI Byte Lane	F4
FSMC_BLN1	VDDIO_FSMC	O	—	FSMC_BLN1	FSMC EMI Byte Lane	F2
FSMC_CLK	VDDIO_FSMC	O	—	FSMC_CLK	FSMC EMI Clk	G3
FSMC_CS0	VDDIO_FSMC	O	—	FSMC_CS0	FSMC EMI Chip Select for External Memory Bank 0	F3
FSMC_CS1	VDDIO_FSMC	O	—	FSMC_CS1	FSMC EMI Chip Select for External Memory Bank 1	E3
FSMC_CS2	VDDIO_FSMC	O	—	FSMC_CS2	FSMC EMI Chip Select for External Memory Bank 2 / IO_Power Sel Ring FSMC	G4
FSMC_DATA0	VDDIO_FSMC	I/O	—	FSMC_DATA0	FSMC EMI data bus	B6

Table 6. FSMC external memory interface pins (continued)

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
FSMC_DATA1	VDDIO_FSMC	I/O	—	FSMC_DATA1	FSMC EMI data bus	A6
FSMC_DATA2	VDDIO_FSMC	I/O	—	FSMC_DATA2	FSMC EMI data bus	D3
FSMC_DATA3	VDDIO_FSMC	I/O	—	FSMC_DATA3	FSMC EMI data bus	A5
FSMC_DATA4	VDDIO_FSMC	I/O	—	FSMC_DATA4	FSMC EMI data bus	C4
FSMC_DATA5	VDDIO_FSMC	I/O	—	FSMC_DATA5	FSMC EMI data bus	A4
FSMC_DATA6	VDDIO_FSMC	I/O	—	FSMC_DATA6	FSMC EMI data bus	C5
FSMC_DATA7	VDDIO_FSMC	I/O	—	FSMC_DATA7	FSMC EMI data bus	D4
FSMC_DATA8	VDDIO_FSMC	I/O	—	FSMC_DATA8	FSMC EMI data bus	A3
FSMC_DATA9	VDDIO_FSMC	I/O	—	FSMC_DATA9	FSMC EMI data bus	B5
FSMC_DATA10	VDDIO_FSMC	I/O	—	FSMC_DATA10	FSMC EMI data bus	E4
FSMC_DATA11	VDDIO_FSMC	I/O	—	FSMC_DATA11	FSMC EMI data bus	B4
FSMC_DATA12	VDDIO_FSMC	I/O	—	FSMC_DATA12	FSMC EMI data bus	C3
FSMC_DATA13	VDDIO_FSMC	I/O	—	FSMC_DATA13	FSMC EMI data bus	B3
FSMC_DATA14	VDDIO_FSMC	I/O	—	FSMC_DATA14	FSMC EMI data bus	E5
FSMC_DATA15	VDDIO_FSMC	I/O	—	FSMC_DATA15	FSMC EMI data bus	D2
FSMC_OUTEN	VDDIO_FSMC	O	—	FSMC_OUTEN	FSMC EMI Output Enable	H2
FSMC_WEN	VDDIO_FSMC	O	—	FSMC_WEN	FSMC EMI Write Enable	F5
FSMC_WTN	VDDIO_FSMC	I	—	FSMC_WTN	FSMC EMI Wait (SNOR, CRAM)	H3

2.7 SQI pins

Table 7. SQI pins

Symbol	I/O voltage	I/O	Description	STA8090EXG
SQI_CEN	VDD_SQI	O	SQI Flash chip enable / IO_Power Sel Ring SQI	H13
SQI_CLK	VDD_SQI	O	SQI Flash clock	H12
SQI_SIO0/SI	VDD_SQI	I/O	SQI Flash data IO 0 / ser. I	G11
SQI_SIO1/SO	VDD_SQI	I/O	SQI Flash data IO 1 / ser. O	G12
SQI_SIO2	VDD_SQI	I/O	SQI Flash data IO 2	G13
SQI_SIO3	VDD_SQI	I/O	SQI Flash data IO 3	H11

2.8 Communication interface pins

Table 8. Communication interface pins

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
CAN0_RX ⁽¹⁾	VDDIO_R2	I	AF0 (default)	CAN0_RX ⁽¹⁾	CAN0 receive data input	E12
		I	AF1	UART0_RX	UART0_Rx data	
		I/O	AF2	Tsense	External temperature capture port	
		I/O	AF3	I2C_SD	I2C serial data	
CAN0_TX ⁽¹⁾	VDDIO_R2	O	AF0 (default)	CAN0_TX ⁽¹⁾	CAN0 transmit data output	F12
		O	AF1	UART0_TX	UART0 Tx data	
		I/O	AF2	GPIO7	General purpose I/O #7	
		O	AF3	I2C_CLK	I2C clock	
I2C_CLK	VDDIO_R2	O	AF0 (default)	I2C_CLK	I2C clock	F13
		I/O	AF1	GPIO8	General purpose I/O #8	
		O	AF2	CAN1_TX ⁽¹⁾	CAN1 transmit data output	
		O	AF3	SPI_CLK	SPI clock	
I2C_SD	VDDIO_R2	I/O	AF0 (default)	I2C_SD	I2C serial data	E13
		I/O	AF1	GPIO9	General purpose I/O #9	
		I	AF2	CAN1_RX ⁽¹⁾	CAN1 receive data input	
		I/O	AF3	SPI_CSN	SPI chip select active low	
SPI_CLK	VDDIO_R1	O	AF0 (default)	SPI_CLK	SPI clock	B11
		I/O	AF1	GPIO25	General purpose I/O #25	
		O	AF2	SQI_CLK	SQI Flash clock	
		O	AF3	MMC_CLK	Multimedia Clock line	
SPI_CSN	VDDIO_R1	O	AF0 (default)	SPI_CSN	SPI chip select active low / IO_Power Sel Ring 1	B12
		I/O	AF1	GPIO24	General purpose I/O #24	
		I/O	AF2	SQI_CEN	SQI Flash chip enable	
		I/O	AF3	MMC_CMD	Multimedia card command line	
SPI_DI	VDDIO_R1	I	AF0 (default)	SPI_DI	SPI serial data input / BOOT2	B10
		I/O	AF1	Tsense	External temperature capture port	
		I/O	AF2	SQI_SIO1/SO	SQI Flash data IO 1 / ser. 0	
		I/O	AF3	MMC_D0	Multimedia card data 0	

Table 8. Communication interface pins (continued)

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
SPI_DO	VDDIO_R1	O	AF0 (default)	SPI_DO	SPI serial data output	B9
		I/O	AF1	GPIO27	General purpose I/O #27	
		I/O	AF2	SQI_SIO0/SI	SQI Flash data IO 0 / ser. 1	
		I/O	AF3	MMC_D1	Multimedia card data 1	
UART0_CTS	VDDIO_R1	I	AF0 (default)	UART0_CTS	UART0 clear to send	A8
		I/O	AF1	GPIO15	General purpose I/O #15	
		O	AF2	i2s_out_sclk	MSP serial clock output	
		O	AF3	Clock GNSS	GNSS clock out	
UART0_DCD	VDDIO_R1	I	AF0 (default)	UART0_DCD	UART0 data carrier detect	C6
		I/O	AF1	GPIO17	General purpose I/O #17	
		O	AF2	i2s_out_sdata	MSP serial data output	
		O	AF3	Clock GNSS	GNSS clock out	
UART0_DSR	VDDIO_R1	I	AF0 (default)	UART0_DSR	UART0 data set ready	A7
		I/O	AF1	GPIO16	General purpose I/O #16	
		O	AF2	i2s_out_lrclk	MSP left/right clock output	
		O	AF3	Sign GC	GLONASS and BeiDou 3-bit coding output (Sign)	
UART0_DTR	VDDIO_R1	O	AF0 (default)	UART0_DTR	UART0 data terminal read	D6
		I/O	AF1	GPIO18	General purpose I/O #18	
		I	AF2	Timer_ICAPA	Extended Function Timer - Input Capture A	
		O	AF3	Mag_1 GG	GPS and Galileo 3-bit coding Output (MAG1)	
UART0_RTS	VDDIO_R1	O	AF0 (default)	UART0_RTS	UART0 request to send	B8
		I/O	AF1	GPIO14	General purpose I/O #14	
		O	AF2	TCXO_OUT	TCXO out clock	
		O	AF3	Sign GG	GPS and Galileo 3-bit coding output (Sign)	
UART0_RX	VDDIO_R1	I	AF0 (default)	UART0_RX	UART0 Rx data	B7
		O	AF1	SPI_DO	SPI serial data output	
		I/O	AF2	SQI_SIO2	SQI Flash data IO 2	
		I	AF3	Timer_ICAPA	Extended Function Timer - Input Capture A	

Table 8. Communication interface pins (continued)

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
UART0_TX	VDDIO_R1	O	AF0 (default)	UART0_TX	UART0 Tx data / BOOT1	C7
		I	AF1	SPI_DI	SPI serial data input	
		I/O	AF2	SQI_SIO3	SQI Flash data IO 3	
		O	AF3	Timer_OCMPA	Extended Function Timer – Output Compare A	
UART2_RX	VDDIO_R1	I	AF0 (default)	UART2_RX	UART2 Rx data	C8
		I/O	AF1	GPIO28	General purpose I/O #28	
		I/O	AF2	I2C_SD	I2C serial data	
		I/O	AF3	MMC_D2	Multimedia card data 2	
UART2_TX	VDDIO_R1	O	AF0 (default)	UART2_TX	UART2 Tx data / BOOT0	D7
		I/O	AF1	GPIO29	General purpose I/O #29	
		O	AF2	I2C_CLK	I2C clock	
		I/O	AF3	MMC_D3	Multimedia card data 2	
USB_DM	VDDIO_R2	USB	AF0	USB_DM	USB D- signal	M1
		I	AF1 (default)	UART1_RX	UART1 Rx data	
		I	AF2	CAN1_RX ⁽¹⁾	CAN1 receive data input	
		I/O	AF3	I2C_SD	I2C serial data	
USB_DP	VDDIO_R2	USB	AF0	USB_DP	USB D+ signal	L1
		O	AF1 (default)	UART1_TX	UART1 Tx data	
		O	AF2	CAN1_TX ⁽¹⁾	CAN1 transmit data output	
		O	AF3	I2C_CLK	I2C clock	

1. Only for STA8090EXGBD and STA8090EXGB.

2.9 Multimedia card pins

Table 9. Multimedia card pins

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
MMC_CLK	VDDIO_R2	O	AF0 (default)	MMC_CLK	Multimedia Clock line	L7
		O	AF1	i2s_out_lrclk	MSP left/right clock output	
		I	AF2	Timer_ICAPA	Extended Function Timer - Input Capture A	
		I/O	AF3	GPIO4	General purpose I/O #4	
MMC_CMD	VDDIO_R2	I/O	AF0 (default)	MMC_CMD	Multimedia card command line	N7
		O	AF1	i2s_out_sdata	MSP serial data output	
		O	AF2	CAN0_TX ⁽¹⁾	CAN0 transmit data output	
		I/O	AF3	GPIO5	General purpose I/O #5	
MMC_D0	VDDIO_R2	I/O	AF0 (default)	MMC_D0	Multimedia card data 0	N6
		O	AF1	i2s_out_sclk	MSP serial clock output	
		I/O	AF2	I2C_SD	I2C serial data	
		I/O	AF3	GPIO20	General purpose I/O #20	
MMC_D1	VDDIO_R2	I/O	AF0 (default)	MMC_D1	Multimedia card data 1	K7
		I	AF1	i2s_in_sdata	MSP serial data input	
		O	AF2	Sign GC	GLONASS and BeiDou 3-bit coding output (Sign)	
		I/O	AF3	GPIO21	General purpose I/O #21	
MMC_D2	VDDIO_R2	I/O	AF0 (default)	MMC_D2	Multimedia card data 2	M7
		I/O	AF1	Reserved	Reserved	
		I	AF2	CAN0_RX ⁽¹⁾	CAN0 receive data input	
		I/O	AF3	Tsense	External temperature capture port	
MMC_D3	VDDIO_R2	I/O	AF0 (default)	MMC_D3	Multimedia card data 3	K8
		I/O	AF1	Reserved	Reserved	
		O	AF2	Sign GG	GPS 3-bit coding output (Sign)	
		I/O	AF3	GPIO23	General purpose I/O #23	

1. Only for STA8090EXGBD and STA8090EXGB.

2.10 General purpose pins

Table 10. General purpose pins

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
GPIO0	VDDIO_R1	I/O	AF0 (default)	GPIO0	General purpose I/O #0	E9
		I	AF1	PPS_IN	Pulse per second input	
		O	AF2	Timer_OCMPB	Extended Function Timer – Output Compare B	
		O	AF3	Mag_0 GC	GLONASS and BeiDou 3-bit coding Output (MAG0)	
GPIO1	VDDIO_R1	I/O	AF0 (default)	GPIO1	General purpose I/O #1 / BOOT3	E8
		I	AF1	i2s_in_sdata	MSP serial data input	
		O	AF2	PPS_OUT	Pulse per second output	
		I/O	AF3	Tsense	External temperature capture port	
GPIO2	VDDIO_R2	I/O	AF0 (default)	GPIO2	General purpose I/O #2	J12
		I	AF1	Reserved	Reserved	
		I	AF2	Timer_ICAPB	Extended Function Timer - Input Capture B	
		O	AF3	Mag_1 GC	GLONASS and BeiDou 3-bit coding Output (MAG1)	
GPIO3	VDDIO_R2	I/O	AF0 (default)	GPIO3	General purpose I/O #3	J11
		I	AF1	Reserved	Reserved	
		O	AF2	Timer_OCMPA	Extended Function Timer – Output Compare A	
		O	AF3	Mag_0 GG	GPS and Galileo 3-bit coding Output (MAG0)	
GPIO10	VDDIO_R2	I/O	AF0 (default), AF1	GPIO10	General purpose I/O #10	L9
		I	AF2	Timer_ICAPA	Extended Function Timer - Input Capture A	
		O	AF3	Timer_OCMPB	Extended Function Timer – Output Compare B	
GPIO11	VDDIO_R2	I/O	AF0 (default), AF1	GPIO11	General purpose I/O #11	J9
		O	AF2	Timer_OCMPA	Extended Function Timer – Output Compare A	
		I	AF3	Timer_ICAPB	Extended Function Timer - Input Capture B	

Table 10. General purpose pins (continued)

Symbol	I/O voltage	I/O	Alternative function	Function	Description	STA8090EXG
GPIO12	VDDIO_R2	I/O	AF0 (default), AF1, AF2, AF3	GPIO12	General purpose I/O #12	L8
GPIO13	VDDIO_R2	I/O	AF0 (default), AF1, AF2, AF3	GPIO13	General purpose I/O #13	K9
GPIO19	VDDIO_R2	I/O	AF0 (default), AF1, AF2, AF3	GPIO19	General purpose I/O #19	J8

2.11 RF front-end pins

Table 11. RF front-end pins

Symbol	I/O voltage	I/O	Description	STA8090EXG
ANT_SENSE1	3.3 V	I	Antenna sensing input 1	M13
ANT_SENSE2	3.3 V	I	Antenna sensing input 2	L12
LNA_IN	1.2 V	I	Low Noise Amplifier Input	N10
XTAL_IN	1.2 V	I	Input Side of Crystal Oscillator or TCXO Input	K12
XTAL_OUT	1.2 V	O	Output Side of Crystal Oscillator	K13

3 General description

3.1 RF front end

The RF front-end is able to down-convert both the GPS-Galileo signal from 1575.42 MHz to 4.092 MHz (4 Fo, being F0 = 1.023 MHz), the GLONASS signal from 1601.718 MHz to 8.57 MHz and the BeiDou signal from 1561.098 MHz to 10.23 MHz.

It embeds high performance LNA minimizing external component count and a LDO to supply the internal core facilitating requirements for external power supply. A three bits ADC converts the IF signals to sign (SIGN) and magnitude (MAG0 and MAG1). They can be sampled or not by SPI. The magnitude bits are internally integrated in order to control the variable gain amplifiers. The VGA gain can be also set by the SPI interface.

The RF tuner accepts a wide range of reference clocks (10 to 52 MHz) and can generate 64 Fo sampling clock for the baseband and 192 Fo clock for MCU subsystem.

3.2 GPS/Galileo/GLONASS/BeiDou Base Band (G3BB+) processor

STA8090EXG integrates G3BB+ proprietary IP, which is the ST last generation high-sensitivity Baseband processor fully compliant with GPS, Galileo, GLONASS and BeiDou systems.

The baseband receives, from the embedded RF Front-End, two separate IF signals coded in sign-magnitude digital format on 3 bits and the related clocks. The Galileo/GPS (GALGPS) and GLONASS/BeiDou (GNSCOM) signals at the base band inputs are centered on 4.092 MHz, 8.57 MHz and 10.23 MHz.

The baseband processes the two IF signals performing data codification, sample rate conversion and final frequency conversion to zero IF before acquisition and tracking correlations.

The baseband processor has the capability of acquiring and tracking the Galileo, GPS, GLONASS and BeiDou signals in a simultaneous or single way, or a combination of three, being GLONASS and BeiDou mutually exclusive. The number of tracking channels to be used is programmable; the not used tracking channels can be powered down.

A complete multi-OS software library is provided by ST to handle GPS processing, managing satellite acquisition, tracking, pseudo-range calculation and positioning, generating the output in the standard NMEA message format or in a ST binary format. The library includes support of ST self-trained assisted GPS (ST-AGPS), a complete and scalable solution for assisting GPS start-up with autonomous and server-based ephemeris prediction and extension.

3.3 MCU Subsystem

The implemented sub-system includes an AHB Lite bus matrix.

An ARM946 core is embedded in the sub-system and masters the AHB bus. The totally available TCM SRAM is 256 KB. The amount of memory on ITCM and DTCM can be

configured by the ARM946 (see [Table 12: TCM Configuration](#)). ITCM can be configured as $N_i \times 16$ KB; DTCM can be configured as $128 + N_d \times 16$ KB, where $N_i + N_d = 8$, $N_i \geq 1$.

Table 12. TCM Configuration

TCMcfg [2]	TCMcfg [1]	TCMcfg [0]	ITCM	DTCM
0	0	0	16 KB	240 KB
0	0	1	32 KB	224 KB
0	1	0	48 KB	208 KB
0	1	1	64 KB	192 KB
1	0	0	80 KB	176 KB
1	0	1	96 KB	160 KB
1	1	0	112 KB	144 KB
1	1	1	128 KB	128 KB

3.3.1 AHB slaves

- G3 APB port that allows to interface with the G3BB acquisition memory and control registers.
- 512 Kbytes ROM
- Vectored Interrupt Controller (VIC).
- FSMC external memory interface
- SQI flash memory controller
- 3 x ARM946 APB peripheral bus (APB1, APB2, APB3).

Vectored Interrupt Controller (VIC)

This Vectored Interrupt Controller (VIC) allows the operative system interrupt handler to quickly dispatch interrupt service routines in response to peripheral interrupts. It provides a software interface to the interrupt system. There are up to 64 interrupt lines. The VIC uses a bit position for each different interrupt source.

The software can control each request line to generate software interrupts. Each interrupt line can be independently enabled and configured to trigger a non-vectored Normal Interrupt Request (IRQ) or Fast Interrupt Request (FIQ) to the ARM946 CPU. Sixteen interrupt lines can also be selected to trigger a vectored IRQ.

The VIC has two operation modes: the user mode and the privilege mode, in order to have the possibility to set (or not) one level of protection during execution.

FS USB device controller

Full speed USB device with transceiver. It is an AHB slave. When active requires a 48 MHz clock XTAL_IN.

FSMC external memory interface

16-bit non-muxed memory interface for burst NOR Flash, SRAM and NAND.

SQL Flash interface

STA8090EXG includes a high-performance interface to Serial Quad Interface (SQI) NOR Flash chips, to support a low-cost simple implementation.

3.4 APB peripherals

3.4.1 CAN

The 2 CAN^(a) cores perform communication according to the CAN protocol version 2.0 part A and B. The bit rate can be programmed to values up to 1 MBit/s. For the connection to the physical layer, additional transceiver hardware is required.

CAN consists of the CAN core, message RAM, message handler, control registers and module. For communication on a CAN network, individual message objects are configured. The message objects and identifier masks for acceptance filtering of received messages are stored in the message RAM. All functions concerning the handling of messages are implemented in the message handler. These functions include acceptance filtering, the transfer of messages between the CAN core and the message RAM, and the handling of transmission requests as well as the generation of the module interrupt.

The register set of the CAN can be accessed directly by the CPU through the module interface. These registers are used to control/configure the CAN core and the message handler and to access the message RAM.

CAN features

- Supports CAN protocol version 2.0 part A and B
- 32 messages objects
- Each message object has its own identifier mask
- Maskable interrupt
- Disabled automatic re-transmission mode for time triggered CAN applications
- Programmable loop-back mode for self-test operation
- Two 16-bit module interfaces to the AMBA APB bus from ARM

3.4.2 EFT

The Extended Function Timer (EFT) consists of a 16-bit counter driven by a programmable prescaler.

It may be used for a variety of purposes, including pulse length measurement of up to two input signals (input capture), generation of up to two output waveforms (output compare) and one PWM generation. Pulse lengths and waveform periods can be modulated from a very wide range using the timer prescaler.

a. Only for STA8090EXGBD and STA8090EXGB (see [Figure 5: Ordering information scheme](#)).

EFT features

- Programmable prescaler: f_{APB} divided from 1 to 256, prescaler register (0 to 255) value +1.
- Overflow status flag and maskable interrupts.
- Output compare functions with:
 - 2 dedicated 16-bit registers
 - 2 dedicated programmable signals
 - 2 dedicated status flags
 - 2 dedicated interrupt flags
- Input capture functions with:
 - 2 dedicated 16-bit registers
 - 2 dedicated active edge selection signals
 - 2 dedicated status flags
 - 2 dedicated interrupt flags
- Pulse Width Modulation mode (PWM).
- One Pulse Mode (OPM).
- PWM input mode.
- Timer global interrupt (5 internally ORed)
 - ICIA: timer input capture A interrupt
 - ICIB: timer input capture B interrupt
 - OCIA: timer output compare A interrupt
 - OCIB: timer output compare B interrupt
 - TOI: timer overflow interrupt

3.4.3 SSP

The SSP is a master interface for synchronous serial communication with peripheral devices that have Motorola SPI.

The SSP performs serial-to-parallel conversion on data received from a peripheral device on SPI_DI pin, and parallel-to-serial conversion on data written by CPU for transmission on SPI_DO pin. The transmit and receive paths are buffered with internal FIFO memories allowing up to 32 x 32-bit values to be stored independently in both transmit and receive modes. FIFOs may be burst-loaded or emptied by the system processor or DMA, from one to eight words per transfer. Each 32-bit word from the system fills one entry in FIFO.

The SSP includes a programmable bit rate clock divider and prescaler to generate the serial output clock SSPCLK from the on-chip clock. One combined interrupt is delivered, which is asserted from several internal maskable events.

SSP features

The SSP has the following features:

- Parallel-to-serial conversion on data written to an internal 32-bit wide, 32-location deep transmit FIFO
- Serial-to-parallel conversion on received data, buffering it in a 32-bit wide, 32-location deep receive FIFO
- Programmable data frame size from 4 to 32 bits
- Programmable clock bit rate and prescaler
- Programmable clock phase and polarity in SPI mode

3.4.4 UART

The UARTx (x = 0|1|2) performs serial-to-parallel conversion on data asynchronously received from a peripheral device on UARTx_RX pin, and parallel-to-serial conversion on data written by CPU for transmission on UARTx_TX pin. The transmit and receive paths are buffered with internal FIFO memories allowing up to 64 data byte for transmission, and 64 data byte with 4-bit status (break, frame, parity, and overrun) for receive.

UART features

The UARTx (x = 0|1|2) are Universal Asynchronous Receiver/Transmitter that support much of the functionality of the industry-standard 16C650 UART. The main features are:

- Programmable baud rates up to $\text{UARTCLK} / 16$ (1.5 Mbps with UARTCLK at 24 MHz), or up to $\text{UARTCLK} / 8$ (3.0 Mbps with UARTCLK at 24 MHz), with fractional baud-rate generator
- 5, 6, 7 or 8 bits of data
- Even, odd, stick or no-parity bit generation and detection
- 1 or 2 stop bit generation
- Support of the modem control functions CTS, RTS, DCD, DSR, RTS, DTS and RI (UART0 only)
- Support of software flow control using programmable Xon/Xoff characters
- False start bit detection
- Line break generation and detection
- Separate 8-bit wide, 64-deep transmit FIFO and 12-bit wide, 64-deep receive FIFO
- Programmable FIFO disabling for 1-byte depth data path

These UARTs vary from industry-standard 16C650 on some minor points which are:

- Receive FIFO trigger levels
- The internal register map address space, and the bit function of each register differ
- The deltas of the modem status signals are not available
- 1.5 stop bits is not supported
- Independent receive clock feature is not supported

3.4.5 I2C

STA8090EXG includes an I2C interface configurable as master or slave.

3.4.6 SDMMC

STA8090EXG features an SD/MMC host.

3.4.7 MTU

The 2 Multi Timer Units provide access to eight interrupt generating programmable 32-bit Free-Running decrementing Counters (FRCs). The FRCs have their own clock input, allowing the counters to run from a much slower clock than the system clock.

The FRC is the part of the timer that performs the counting. There are four instantiations of the FRC block in each MTU, allowing eight counts to be performed in parallel. The 32-bit counter in the FRC is split up into two 16-bit counters.

3.4.8 WDT

Watchdog Timer (WDT) provides a way of recovering from software crashes. The watchdog clock is used to generate a regular interrupt (WDOGINT), depending on a programmed value.

The watchdog monitors the interrupt and asserts a reset signal (WDOGRES) if the interrupt remains unserved for the entire programmed period. You can enable or disable the watchdog unit as required.

Note: Watchdog is stalled when the ARM processor is in Debug mode.

3.4.9 GPIO

The GPIO block provides thirty-seven (37) programmable inputs or outputs. Each input or output can be controlled in two modes:

- software mode through an APB bus interface
- alternate mode, where GPIO becomes a peripheral input or output line

Any GPIO input can be independently enabled or disabled (masked) for interrupt generation. User can select for each GPIO which edge (rising, falling, both) will trigger an interrupt.

3.4.10 ADC

10 bit SAR ADC operating at 1.8 V analog supply. It can convert up to 8 single ended channels with analog input multiplexer at 500KSPS

3.4.11 RTC

This is an always-on power domain dedicated to RTC logic (backup system) with 32 Kbyte SRAM and supplied with a dedicated voltage regulator.

The RTC provides a high resolution clock which can be used for GPS. It keeps the time when the system is inactive and can be used to wake the system up when a programmed alarm time is reached. It has a clock trimming feature to compensate for the accuracy of the 32.768 kHz crystal and a secured time update.

RTC features

- 47-bit counter clocked by 32.768 kHz clock
- 32-bit for the integer part (seconds) and 15-bit for the fractional part
- The integer part and the fractional part are readable independently
- The counter, once enabled, can be stopped
- Integer part load register (32-bit)
- Fractional part load register (15-bit)
- Load bit to transfer the content of the entire load register (integer+fractional part) to the 47-bit counter. Once set by the MCU this bit is cleared by the hardware to signal to the MCU that the RTC has been updated.

3.4.12 MSP

The STA8090EXG provides one MSP transmitter block.

- Element (data) size from 8 to 32 bits, LSB or MSB first
- Programmable frequency shift clock for data transfer
- Direct interface to:
 - industry-standard codecs and serially connected A/D and D/A devices
 - IIS compliant devices
 - SPI compliant devices
- Transmit first-in, first-out memory buffers (FIFOs), 32 bit wide, 8 locations deep

4 Electrical characteristics

4.1 Parameter conditions

Unless otherwise specified, all voltages are referred to GND.

4.2 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at $T_A = 25^\circ\text{C}$.

4.3 Typical values

Unless otherwise specified, typical data are based on $T_A = 25^\circ\text{C}$, $V_{\text{ddio}} = 1.8\text{ V}$, $V_{\text{dd}} = 1.20\text{ V}$. They are given only as design guidelines and are not tested.

4.4 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

4.5 Absolute maximum ratings

This product contains devices to protect the inputs against damage due to high static voltages, however it is advisable to take normal precautions to avoid application of any voltage higher than the specified maximum rated voltages.

[Table 13](#) lists the absolute maximum rating for STA8090EXG.

Table 13. Voltage characteristics

Symbol	Parameter	Min.	Max.	Unit
$V_{\text{CC_CHAIN}}$	Analog supply voltage for RF chain (1.2 V)	-0.3	1.32	V
$V_{\text{CC_PLL}}$	Analog supply voltage for PLL RF (1.2 V)	-0.3	1.32	V
$V_{\text{CC_RF}}$	Analog supply voltage for RF (1.2 V)	-0.3	1.32	V
$V_{\text{DD_ADC}}$	Digital supply voltage for ADC (1.8 V)	-0.3	1.98	V
$V_{\text{DD_SQI}}$	Digital supply voltage for SQI	-0.3	3.63	V
V_{DDD}	Power supply pins for the core logic.	-0.3	1.32	V
$V_{\text{DDIO_FSMC}}$	Digital supply voltage for FSMC I/O ring (1.8 V or 3.3 V)	-0.3	3.63	V
$V_{\text{DDIO_R1}}$	Digital supply voltage for I/O ring 1 (1.8 V or 3.3 V)	-0.3	3.63	V
$V_{\text{DDIO_R2}}$	Digital supply voltage for I/O ring 2 (3.3 V)	-0.3	3.63	V
V_{INB}	Backup LDO input supply voltage (1.6 V to 4.3 V)	-0.3	4.8	V

Table 13. Voltage characteristics (continued)

Symbol	Parameter	Min.	Max.	Unit
V _{INL1}	LDO1 input supply voltage (1.6 V to 4.3 V)	-0.3	4.8	V
V _{INL2}	LDO2 input supply voltage (1.6 V to 4.3 V)	-0.3	4.8	V
V _{INM}	SMPS coil input supply (1.6 V to 4.3 V)	-0.3	4.8	V
V _{DD_ANA}	SMPS input supply (1.6 V to 4.3 V)	-0.3	4.8	V
V _{ESD-HBM}	Electrostatic discharge, human body model ⁽¹⁾	-2	2	kV
V _{ESD-CDM}	Electrostatic discharge, charge device model ⁽²⁾	-250	250	V

1. Balls sustaining only ± 500 V are: A1, A2, A9, A10, A11, A12, A13, B1, B2, B13, C1, C2, D1, E1, E2, E10, E11, F1, N11, N12, N13.

2. Ball N10 (LNA_IN) sustains only ± 100 V.

Note: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 14. Thermal characteristics

Symbol	Parameter	Min.	Max.	Unit
T _{oper}	Operative ambient temperature	-40	85	°C
T _j	Operative junction temperature	-40	125	°C
T _{st}	Storage temperature	-55	150	°C
R _{j-amb}	Thermal resistance junction to ambient ⁽¹⁾		41	°C/W

1. According to JEDEC specification on a 2 layers board.

Table 15. Frequency limits

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
F _{CLK}	Operating ARM9 CPU frequency	V _{DDD} = 1.2 V; T _C = 85 °C ⁽¹⁾	—	—	196	MHz
F _{AHB}	AHB frequency		—	—	49	MHz

1. Not tested in production.

Table 16. Power consumption

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
P_{RF}	RFIP power (total V_{INL2})	G2 = GPS/Galileo; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{INL2} = 1.8\text{ V}$	—	25	—	mW
		G2 + GLONASS; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{INL2} = 1.8\text{ V}$	—	35	—	mW
		G2 + BeiDou; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{INL2} = 1.8\text{ V}$	—	35	—	mW
$P_{MVR}^{(1)}$	Switchable area power; (total V_{INL1})	$f_{ARM} = 196\text{ MHz}$; $f_{AHB} = 49\text{ MHz}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{INL1} = 1.8\text{ V}$; UART active; other peripherals inactive	—	90	—	mW
$P_{LPVR}^{(1)}$	Always ON area power (total V_{INB})	$f_{ARM} = 196\text{ MHz}$; $f_{AHB} = 49\text{ MHz}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{INB} = 3.3\text{ V}$	—	1	—	mW
$P_{IO}^{(1)}$	IO rings power (total $V_{DDIO_R1} + V_{DDIO_R2}$)	$f_{ARM} = 196\text{ MHz}$; $f_{AHB} = 49\text{ MHz}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{INL1} = 1.8\text{ V}$; UART active; other peripherals inactive	—	4	—	mW
$I_{DStandby}$	Standby mode supply current	RTC running = 32.768 KHz;	—	29	—	μA
$I_{DDepStandby}$	Deep standby mode supply current ⁽²⁾	$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{INB} = 1.8\text{ V}$	—	7	—	μA

1. Not tested in production.

2. STDBY_OUT pin not supported in deep standby.

4.6 Recommended DC operating conditions

Table 17 lists the functional recommended operating DC parameters for STA8090EXG.

Table 17. Recommended DC operating conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{CC_CHAIN}	Analog supply voltage for RF chain (1.2 V)	1.08	1.20	1.32	V
V_{CC_PLL}	Analog supply voltage for PLL RF (1.2 V)	1.08	1.20	1.32	V
V_{CC_RF}	Analog supply voltage for RF (1.2 V)	1.08	1.20	1.32	V
V_{DD_ADC}	Digital supply voltage for ADC (1.8 V)	1.71	1.80	1.89	V
V_{DD_SQI}	Digital supply voltage for SQI I/O ring (1.8 V)	1.71	1.80	1.89	V
	Digital supply voltage for SQI I/O ring (3.3 V)	3.00	3.30	3.60	V

Table 17. Recommended DC operating conditions (continued)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V _{DDD}	Power supply pins for the core logic.	1.00	1.10	1.32	V
V _{DDIO_FSMC}	Digital supply voltage for FSMC I/O ring (1.8 V)	1.71	1.80	1.89	V
	Digital supply voltage for FSMC I/O ring (3.3 V)	3.00	3.30	3.60	V
V _{DDIO_R1}	Digital supply voltage for I/O ring 1 (1.8 V)	1.71	1.80	1.89	V
	Digital supply voltage for I/O ring 1 (3.3 V)	3.00	3.30	3.60	V
V _{DDIO_R2}	Digital supply voltage for I/O ring 2 (3.3 V)	3.00	3.30	3.60	V
V _{INB}	Backup LDO input supply voltage (1.6 V to 4.3 V)	1.60		4.30	V
V _{INL1}	LDO1 input supply voltage to generate 1.1 V and 1.2 V	1.60		4.30	V
	LDO1 input supply voltage to generate 1.8 V	2.10		4.30	V
V _{INL2}	LDO2 input supply voltage to generate 1.2 V	1.60		4.30	V
V _{INM}	SMPS coil input supply voltage to generate 1.1 V and 1.2 V	1.60		4.30	V
	SMPS coil input supply voltage to generate 1.8 V	2.10		4.30	V
V _{DD_ANA}	SMPS input supply (1.6 V to 4.3 V)	1.60		4.30	V
T _C	Operating case temperature	-40		85	°C

4.7 DC characteristics

Table 18 specifies the SMPS voltage regulator characteristics.

Table 18. SMPS DC characteristics

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V _{OM}	Output voltage (1.2 V)	$1.6\text{ V} \leq V_{INM} \leq 4.3\text{ V};$ $I_{OM} \leq 100\text{ mA}$	1.08	1.20	1.32	V
	Output voltage (1.1 V)	$1.6\text{ V} \leq V_{INM} \leq 4.3\text{ V};$ $I_{OM} \leq 100\text{ mA}$	1.0	1.10	1.32	V
	Output voltage (1.8 V)	$2.1\text{ V} \leq V_{INM} \leq 4.3\text{ V};$ $I_{OM} \leq 100\text{ mA}$	1.72	1.80	1.98	V
I _{OM}	Output current		0	—	100	mA

Table 19 specifies the LDO1 voltage regulator characteristics.

Table 19. LDO1 DC characteristics

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V _{OL1}	Output voltage (1.2V)	$1.6\text{ V} \leq V_{\text{INL1}} \leq 4.3\text{ V};$ $I_{\text{OL1}} \leq 70\text{ mA}$	1.08	1.20	1.32	V
	Output voltage (1.1V)	$1.6\text{ V} \leq V_{\text{INL1}} \leq 4.3\text{ V};$ $I_{\text{OL1}} \leq 70\text{ mA}$	1.0	1.10	1.32	V
	Output voltage (1.8V)	$2.1\text{ V} \leq V_{\text{INL1}} \leq 4.3\text{ V};$ $I_{\text{OL1}} \leq 70\text{ mA}$	1.72	1.80	1.98	V
I _{OL1}	Output current		0	—	70	mA

Table 20 specifies the LDO2 voltage regulator characteristics.

Table 20. LDO2 DC characteristics

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V _{OL2}	Output voltage	$1.6\text{ V} \leq V_{\text{INL2}} \leq 4.3\text{ V};$ $I_{\text{OL2}} \leq 30\text{ mA}$	1.08	1.20	1.32	V
I _{OL2}	Output current		0	—	30	mA

Table 21 specifies the low voltage detection thresholds

Table 21. Low voltage detection thresholds

Parameter		Min.	Typ.	Max.	Unit
Input LVD always on and main VRs ⁽¹⁾	Upper voltage threshold	—	1.680	—	V
	Lower voltage threshold	—	1.650	—	V
Output LVD always on VR ⁽¹⁾	Upper voltage threshold	—	0.995	—	V
	Lower voltage threshold	—	0.935	—	V
Output LVD main VR (1.1 V) ⁽¹⁾	Upper voltage threshold @ V _{OL1/M} = 1.2 V	—	1.142	—	V
	Lower voltage threshold @ V _{OL1/M} = 1.2 V	—	1.076	—	V
	Upper voltage threshold @ V _{OL1/M} = 1.1 V	—	1.048	—	V
	Lower voltage threshold @ V _{OL1/M} = 1.1 V	—	0.986	—	V
Output LVD main VR (1.8 V) ⁽¹⁾	Upper voltage threshold @ V _{OL1/M} = 1.8 V	—	1.645	—	V
	Lower voltage threshold @ V _{OL1/M} = 1.8 V	—	1.626	—	V

1. Not tested in production.

Table 22 lists the DC characteristics for all the IO digital buffers except for the following input buffers: STBYn (H9), STDBY_OUT (J10), WAKEUP0 (F11), WAKEUP1 (F10), PMU_CFG (H10) and RSTn (G9).

Table 22. I/O buffers DC characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IL}^{(1)}$	Logical input low level voltage	$V_{DDIO} = 1.8\text{ V}$	-0.3	—	$0.3 * V_{DDIO}$	V
		$V_{DDIO} = 3.3\text{ V}$	-0.3	—	0.8	V
$V_{IH}^{(1)}$	Logical input high level voltage	$V_{DDIO} = 1.8\text{ V}$	$0.7 * V_{DDIO}$	—	$V_{DDIO} + 0.3$	V
		$V_{DDIO} = 3.3\text{ V}$	2.0	—	$V_{DDIO} + 0.3$	V
$V_{HYST}^{(2)}$	Schmitt-trigger hysteresis	—	50	—		mV
V_{OL}	Low level output voltage	$V_{DDIO} = 1.8\text{ V}$		—	0.4	V
		$V_{DDIO} = 3.3\text{ V}$		—	0.4	V
V_{OH}	High level output voltage	$V_{DDIO} = 1.8\text{ V}$	$V_{DDIO} - 0.4$	—		V
		$V_{DDIO} = 3.3\text{ V}$	$V_{DDIO} - 0.4$	—		V

1. Excludes oscillator inputs RTC_XTI and XTAL_IN. Refer to oscillator electrical specifications.

2. Apply to all digital inputs unless specified otherwise.

Table 23 lists the DC characteristics for the 1.0 V IO digital buffers input buffers: STBYn (H9), STDBY_OUT (J10), WAKEUP0 (F11), WAKEUP1 (F10), PMU_CFG (H10) and RSTn (G9).

Table 23. 1.0 V I/O buffers DC characteristics

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
V_{IL}	Logical input low level voltage	$V_{OB} = 1.0\text{ V}$	-0.3	—	$0.35 * V_{OB}$	V
V_{IH}	Logical input high level voltage	$V_{OB} = 1.0\text{ V}$	$0.65 * V_{OB}$	—	$V_{OB} + 0.3$	V
V_{OL}	Low level output voltage	$V_{OB} = 1.0\text{ V}$		—	0.2	V
V_{OH}	High level output voltage	$V_{OB} = 1.0\text{ V}$	$V_{OB} - 0.2$	—		V

4.8 AC characteristics

4.8.1 RF electrical specifications

Table 24. RFACHAIN – GALGPS filter and VGA

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$S_{11}^{(1)}$	Input return loss	GPS band	—	-8		dB
f_{IF}	IF frequency	PLL in default condition with 26Mhz as reference	—	4.045		MHz
NF	Noise figure	NF overall chain with AGC set at 0 dB	—	2 ⁽¹⁾		dB
C_G	Conversion gain from RF input to ADC input	VGA at max gain	—	119		dB
		VGA at min gain	—	69		dB

Table 24. RFACHAIN – GALGPS filter and VGA (continued)

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
IP _{1dB}	RF-IF-VGA input compression point	VGA min	—	-80		dBm
IRR	Image rejection ratio		—	20		dB
BW _{GPS}	-3dB IF bandwidth	GPS mode	—	2.4		MHz
BW _{GAL}		Galileo mode	—	4.8		MHz
ATT	Alias frequency rejection	F = 60 MHz (fs = 65.474 MHz)	—	30 ⁽¹⁾		dB
T _{gGPS}	IF filter group delay variation	GPS mode	—		200 ⁽¹⁾	ns
T _{gGAL}		Galileo mode	—		30 ⁽¹⁾	ns

1. Not tested in production.

Table 25. RFCHAIN – GLONASS/BeiDou filter and VGA

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
S11 ⁽¹⁾	Input return loss	GLONASS band		-8		dB
		BeiDou band		-8		
f _{IFGNS/BDU}	IF frequency for GLONASS	PLL in default condition with 26 Mhz as reference	—	8.519		MHz
	IF frequency for BeiDou		—	10.277		
NF	Noise figure	NF overall chain with AGC set at 0 dB	—	2 ⁽¹⁾		dB
C _G	Conversion gain from RF input to ADC input	VGA at max gain	—	118		dB
		VGA at min gain	—	68		dB
IP _{1dB}	RF-IF-VGA input compression point	VGA min	—	-80		dBm
IRR	Image rejection ratio		—	30		dB
BW _{GNS/BDU}	-3dB IF bandwidth		—	10		MHz
ATT	Alias frequency rejection	F = 53 MHz (fs = 65.474 MHz)	—	30 ⁽¹⁾		dB
T _{gGNS/BDU}	IF filter group delay variation		—		20 ⁽¹⁾	ns

1. Not tested in production.

Table 26. Synthesizer

Symbol	Parameter	Min.	Typ.	Max.	Unit
F _{TCXO_XTAL}	Input frequency for xtal amplifier ⁽¹⁾	10		55	MHz
R _{DIV}	Reference divider range	1		63	
N _{DIV}	Loop divider range	56		2047	
F _{LO}	LO operating frequency		3142.656		MHz

1. That amplifier can be used also as a TCXO input buffer

4.8.2 Oscillator electrical specifications

This device contains two oscillators:

- a 32.768 kHz oscillator/buffer for RTC circuit.
- an OSCI oscillator/buffer in the RF Front-End

When used in oscillator mode, each oscillator requires a specific crystal, with parameters that must be as close as possible to the following recommended values. When used in input buffer mode, an external clock source must be applied.

32.768 kHz OSCI32 oscillator specifications

The 32.768 kHz OSCI32 oscillator is connected between RTC_XTI (oscillator amplifier input) and RTC_XTO (oscillator amplifier output). It also requires two external capacitors of 18 pF^(b), as shown on [Figure 2](#).

OSCI32 is disabled by default and must be enabled by setting bit28-OSCI_EN of PRCC_BACKUP_REG0 to have 32.768KHz oscillation when an XTAL pi-network is connected to RTC_XTI/RTC_XTO pins.

The recommended oscillator specifications are shown in [Table 27](#):

Table 27. Crystal recommended specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
F _{SXTAL}	Crystal frequency ⁽¹⁾	—	32.768	—	kHz
LM _{SXTAL}	Motion inductance ⁽¹⁾	—	5	—	kH
CM _{SXTAL}	Motional capacitance ⁽¹⁾	—	5.0	—	fF
CO _{SXTAL}	Shunt capacitance ⁽¹⁾	—	1.3	—	pF
ESR	Resonance resistance ⁽¹⁾	—	—	80	kΩ
CL	External load capacitance ⁽¹⁾	—	18	—	pF

1. Not tested in production.

b. Using crystal with recommended characteristics as per [Table 27](#).

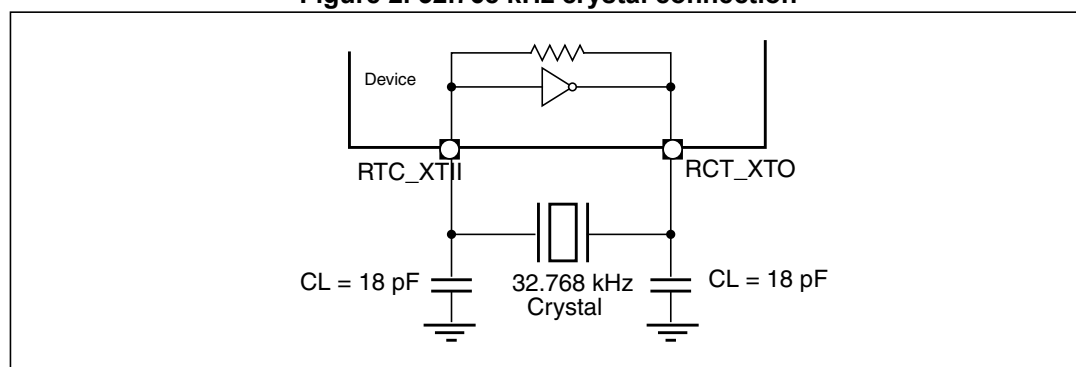
The oscillator amplifier specifications are shown in the following table:

Table 28. Oscillator amplifier specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
T_S	Startup time ⁽¹⁾	—	0.3	0.6	s
DL	Drive level ⁽¹⁾	—	—	<0.1	μW
RLC	Required load capacitance ⁽¹⁾	—	12.5	—	pF
GM	Startup transconductance	22.5	33.6	—	μA/V

1. Not tested in production.

Figure 2. 32.768 kHz crystal connection



To drive the 32.768 kHz crystal pins from an external clock source:

- Disable the oscillator (bit28-OSCI_EN = 0b in PRCC_BACKUP_REG0 register). This disables the internal inverter, thus reducing the power consumption to minimum.
- Drive the RTC_XTI pin with a square signal or a sine wave.

Table 29. Characteristics of external slow clock input

Symbol	Parameter	Min.	Typ.	Max.	Unit
$T_{JIT} (cc)$	Cycle-to-cycle jitter	-70	—	70	ps
$T_{JIT} (per)$	Period jitter	-70	—	70	ps
	Variation	-500	—	500	ppm
T_{DUTY}	Duty cycle	45	—	55	%

4.8.3 OSCI oscillator specifications

The supported values of the embedded BOOT ROM are 16.368 MHz, 24.00 MHz, 26.00 MHz and 48.00 MHz.

The default values supported by the GNSS binary image are 26 MHz and 48 MHz, to enable USB peripheral the 48 MHz is mandatory.

4.8.4 ADC specifications

This section gives the AC specification of the 10 bit Successive Approximation Register ADC embedded in STA8090EXG device. It is controlled by the ARM9 MCU through a

wrapper and an APB bridge as depicted in [Figure 3](#) and it has a maximum conversion rate of 1MSPS with 8 muxed analog input channels capability. An internal voltage reference is used and analog/digital power supplies connections are implemented inside the device without any needs of dedicated external pins.

Figure 3. SARADC connections

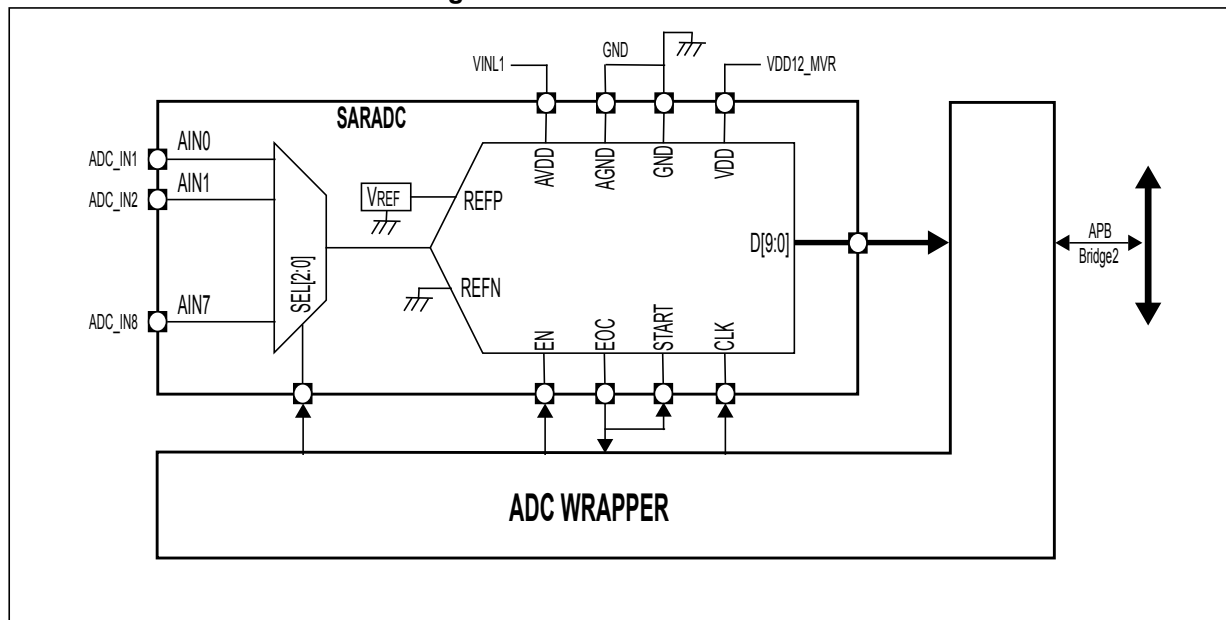


Table 30. SARADC specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{ADCIN}	ADC_IN input range	$V_{GND}-0.3$	—	$V_{DD_ADC}+0.3$	V
V_{ADCCR}	Conversion range	V_{GND}	—	V_{REF}	V
V_{REF}	Voltage reference	1.35	1.4	1.45	V
C_{IN}	Input capacitance ⁽¹⁾	5.5	7.0	8.5	pF
R_{IN}	Input mux resistance (total equivalent sampling resistance) ⁽²⁾	1.5	2.0	2.5	k Ω
F_{CLK}	Clock frequency	2.5		15	MHz
δ_{CLK}	Clock duty cycle	45	50	55	%
T_{SUP}	Start up time ⁽¹⁾⁽³⁾	—	—	20	μ s
T_C	Conversion time	—	14	—	cycles
T_S	Sampling time	—	3		cycles
INL	Performance	—	—	< ± 2	LSB
DNL		—	—	< ± 2	LSB

1. Not tested in production.

2. Pad input capacitance included.

3. From EN = 1.

5 Package and packing information

5.1 ECOPACK® packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.

ECOPACK® is an ST trademark.

5.2 TFBGA169 9 x 9 x 1.2 mm package information

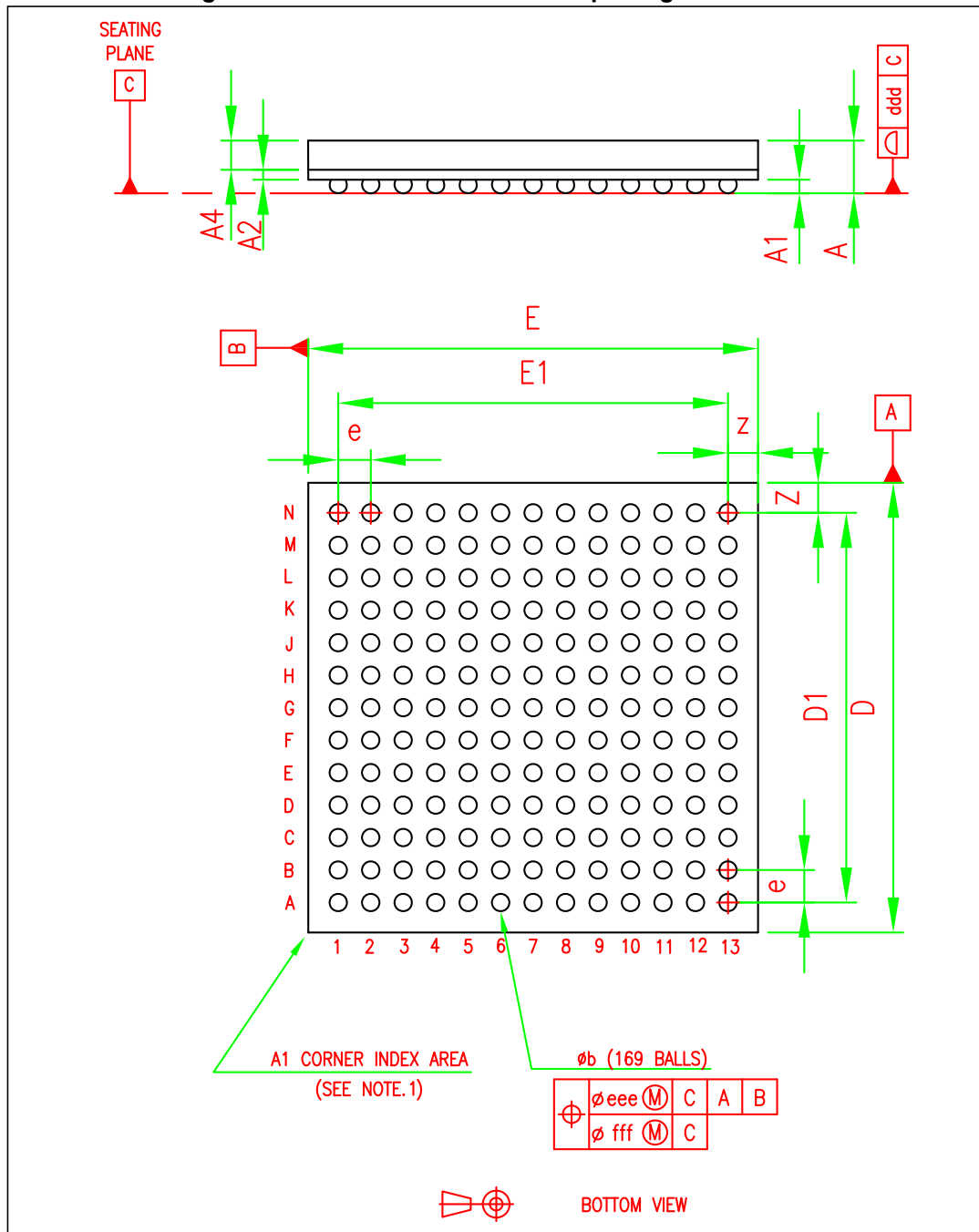
Table 31. TFBGA169 9 x 9 x 1.2 mm mechanical data

Ref. dim	Data book (mm)			Drawing (mm)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A ⁽¹⁾			1.20			1.07
A1 ⁽²⁾	0.21			0.22	0.27	0.32
A2		0.20		0.16	0.20	0.24
A4		0.585		0.57	0.585	0.60
b ⁽³⁾	0.30	0.35	0.40	0.30	0.35	0.40
D	8.85	9.00	9.15	8.90	9.00	9.10
D1		7.80			7.80	
E	9.85	9.00	9.15	8.90	9.00	9.10
E1		7.80			7.80	
e		0.65			0.65	
Z		0.60			0.60	
ddd			0.08			0.08
eee ⁽⁴⁾			0.15			0.15
fff ⁽⁵⁾			0.05			0.05

- TFBGA stands for Thin profile Fine Pitch Ball Grid Array.
 - The total profile height (Dim A) is measured from the seating plane to the top of the component
 - The maximum total package height is calculated by the following methodology:
 $A_{Max} = A1_{Typ} + A2_{Typ} + A4_{Typ} + \sqrt{(A1^2 + A2^2 + A4^2 \text{ tolerance values})}$
 - Thin profile: 1.00 mm < A ≤ 1.20 mm / Fine pitch: e < 1.00 mm pitch.
- The terminal A1 corner must be identified on the top surface by using a corner chamfer, ink or metallized markings, or other feature of package body or integral heatslug.
 - A distinguishing feature is allowable on the bottom surface of the package to identify the terminal A1 corner. Exact shape of each corner is optional.
- The typical ball diameter before mounting is 0.35 mm.
- The tolerance of position that controls the location of the pattern of balls with respect to datums A and B. For each ball there is a cylindrical tolerance zone eee perpendicular to datum C and located on true position with respect to datums A and B as defined by e. The axis perpendicular to datum C of each ball must lie within this tolerance zone.

5. The tolerance of position that controls the location of the balls within the matrix with respect to each other. For each ball there is a cylindrical tolerance zone ϕfff perpendicular to datum C and located on true position as defined by e . The axis perpendicular to datum C of each ball must lie within this tolerance zone. Each tolerance zone ϕfff in the array is contained entirely in the respective zone ϕeee above. The axis of each ball must lie simultaneously in both tolerance zones.

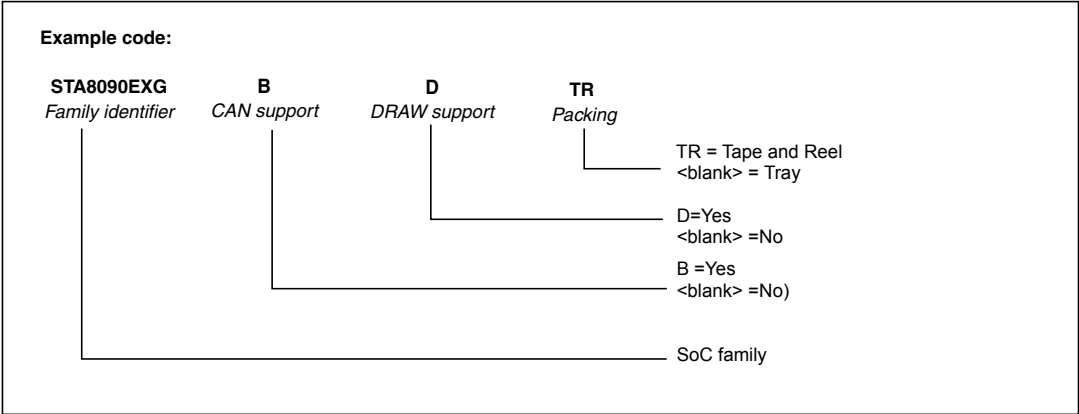
Figure 4. TFBGA169 9 x 9 x 1.2 mm package dimension



1. - The terminal A1 corner must be identified on the top surface by using a corner chamfer, ink or metallized markings, or other feature of package body or integral heatslug.
- A distinguishing feature is allowable on the bottom surface of the package to identify the terminal A1 corner. Exact shape of each corner is optional.

6 Ordering information

Figure 5. Ordering information scheme



7 Revision history

Table 32. Document revision history

Date	Revision	Changes
21-Nov-2014	1	Initial release.
30-Jun-2015	2	Updated Features and Description Updated Chapter 1: Overview Table 3: Power supply pins: – VOL1 VOM, VDDD: updated description Updated Section 3.4.2: EFT and Section 3.4.4: UART Table 16: Power consumption: – P_{RF}: updated typical value for GPS/Galileo – P_{MVR}, P_{LPVR}, P_{IO}: added note – I_{DSLEEP}: updated value Table 17: Recommended DC operating conditions: – V_{INL1}, V_{INL2}, V_{INM}: updated parameters Table 18: SMPS DC characteristics: – V_{OM}: set min and max values as TBD, removed condition for Output voltage at 1.0 V Table 19: LDO1 DC characteristics: – V_{OL1}: set min and max values as TBD, removed condition for Output voltage at 1.0 V Table 20: LDO2 DC characteristics: – V_{OL2}: set min and max values as TBD Table 21: Low voltage detection thresholds: – Output LVD main VR (1.1 V): removed condition for Output voltage at 1.0 V Table 24: RFCHAIN – GALGPS filter and VGA: – S11: Added note – C_G: updated values Table 25: RFCHAIN – GLONASS/BeiDou filter and VGA: – S11: Added note – C_G: updated values Table 28: Oscillator amplifier specifications: – T_S: updated minimum value Updated Section 4.8.3: OSCI oscillator specifications
14-Dec-2015	3	Table 13: Voltage characteristics: – V_{ESD-HBM}, V_{ESD-CDM}: updated values
30-May-2017	4	Changed from STA8090EXGA to STA8090EXGBD Updated Table 16: Power consumption Updated Table 18: SMPS DC characteristics Updated Table 19: LDO1 DC characteristics Updated Table 20: LDO2 DC characteristics Updated Table 25: RFCHAIN – GLONASS/BeiDou filter and VGA Updated Table 26: Synthesizer Updated Figure 5: Ordering information scheme

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